

$^{193}\text{Po}$   $\alpha$  decay (245 ms)    2002Va13,1993Wa04

Type	Author	History	Citation	Literature Cutoff Date
Full Evaluation	T. D. Johnson, Balraj Singh	NDS 142, 1 (2017)		15-Apr-2017

Parent:  $^{193}\text{Po}$ : E=95 7;  $J^\pi=(13/2^+)$ ;  $T_{1/2}=245$  ms 11;  $Q(\alpha)=7094$  4; % $\alpha$  decay $\leq$ 100.0

$^{193}\text{Po}$ -E, $J^\pi$ : From 2013Sa43 from  $E\alpha$  values and decay pattern in  $^{197}\text{Rn} \rightarrow ^{193}\text{Po} \rightarrow ^{189}\text{Pb} \rightarrow ^{185}\text{Hg} \rightarrow ^{181}\text{Pt}$   $\alpha$ -decay chain.

The same values are given in  $^{193}\text{Po}$  Adopted Levels in the ENSDF database (Nov 2015 update). Energy of this state is listed as 100 keV 6 in 2017Au03 from energy difference in  $\alpha$  decay.

$^{193}\text{Po}$ -T<sub>1/2</sub>: From  $^{193}\text{Po}$  Adopted Levels in the ENSDF database (Nov 2015 update).

$^{193}\text{Po}$ -Q( $\alpha$ ): From 2017Wa10.

$^{193}\text{Po}$ -% $\alpha$  decay: % $\alpha\leq$ 100 (from  $^{193}\text{Po}$  Adopted Levels in the ENSDF database; Nov 2015 update).

2002Va13:  $^{193}\text{Po}$  produced by  $^{166}\text{Er}(^{32}\text{S},5\text{n})$ ; implanted into position sensitive silicon strip detector to register the decayed  $\alpha$ -particles; Ge detectors for  $\gamma$  and X-rays; Silicon detectors for conversion electrons;  $E\alpha$ ,  $E\gamma$ ,  $E(\text{ce})$ ,  $\alpha\gamma$  and  $\alpha\text{-ce}$  coincidences measured.

1993Wa04:  $\alpha$ -sources  $^{193}\text{Po}$  produced by <240 MeV Ne beam on 2.1 mg/cm<sup>2</sup>  $^{182}\text{W}$  target; LISOL separator; Silicon surface-barrier detector and silicon PIPS-type detectors;  $E\alpha$ , T<sub>1/2</sub> measured.

See also, 2005Uu02, 1995Mo14, 1981Le23, 1967Si09.

 $^{189}\text{Pb}$  Levels

E(level)	$J^\pi$	Comments
40 4	(13/2 <sup>+</sup> )	Additional information 1. $E(\text{level})$ : from 2013Sa43.
677 1	(13/2 <sup>+</sup> )	$J^\pi$ : from $^{189}\text{Pb}$ Adopted Levels. $E(\text{level}), J^\pi$ : from 2013Sa43. The same $J^\pi$ value in Adopted Levels.

 $\alpha$  radiations

$E\alpha$	E(level)	$I\alpha^\ddagger$	$HF^\dagger$	Comments
6375 15	677	0.8 3	1.1 5	$E\alpha, I\alpha$ : from 2002Va13.
7002 4	40	99.2 3	2.0 1	$E\alpha$ : weighted average of 7004 10 (2002Va13), 6991 20 (1995Mo14), 7004 5 (1993Wa04), 7000 20 (1981Le23) and 6980 20 (1967Si09). Other: 6995 keV (1977De32). $I\alpha$ : 99.2 35 in 2002Va13. Uncertainty of 0.3 is assigned by evaluators based on 100-( $I\alpha$ =0.8 3 to 677 level).

<sup>†</sup> Deduced by evaluators using  $r_0(^{189}\text{Pb})=1.511$  8, from  $r_0(^{188}\text{Pb})=1.511$  8 and  $r_0(^{190}\text{Pb})=1.511$  6 (1998Ak04).

<sup>‡</sup> For absolute intensity per 100 decays, multiply by  $\leq 1$ .

 $\gamma(^{189}\text{Pb})$ 

$E_\gamma$	$I_\gamma^\dagger$	$E_i(\text{level})$	$J_i^\pi$	$E_f$	$J_f^\pi$	Mult.	$\alpha^\ddagger$	$I_{(\gamma+\text{ce})}^\dagger$	Comments
637 1	67 9	677	(13/2 <sup>+</sup> )	40	(13/2 <sup>+</sup> )	E0+M1+E2	0.49 19	99.2 3	$I_{(\gamma+\text{ce})}$ : from $I_\gamma$ . $I_\gamma$ : from $I(\gamma+\text{ce})$ and $\alpha(\text{exp})$ . Mult.: $\alpha(\text{exp})=1.1$ 4 (2002Va13). $\alpha(\text{exp})$ : from Adopted Gammas, based on $a(K)\text{exp}=0.41$ 16 (2009Dr03).

<sup>†</sup> For absolute intensity per 100 decays, multiply by  $\leq 1$ .

<sup>‡</sup> Total theoretical internal conversion coefficients, calculated using the BrIcc code (2008Ki07) with Frozen orbital approximation based on  $\gamma$ -ray energies, assigned multipolarities, and mixing ratios, unless otherwise specified.

$^{193}\text{Po}$   $\alpha$  decay (245 ms)    2002Va13,1993Wa04Decay SchemeIntensities:  $I_{(\gamma+ce)}$  per 100 parent decays